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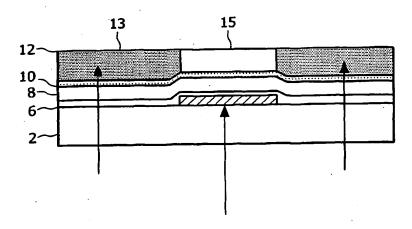
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(54) Title: TRANSISTOR MANUFACTURE



(57) Abstract: A method of making a source-gated transistor is described, in which a gate (4) is provided on substrate (2) followed by gate insulator (6) and semiconductor layer (8). The layer is patterned to align the source with the gate (4) using photoresist (12) and back illumination through the substrate (2) with the gate (4) acting as a mask. The distance between source and drain may also be self-aligned using a spacer technique.

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